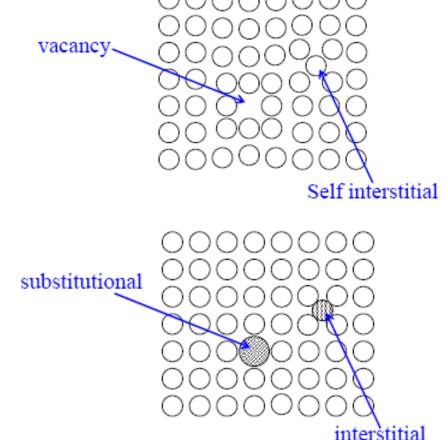
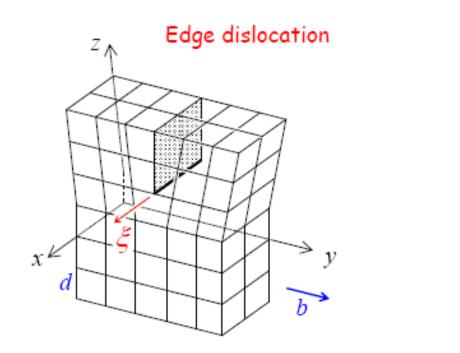
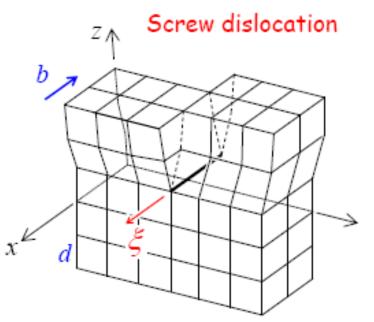
- Point defects (0-D):
  - Vacancy, impurity, interstitial and substitutional atoms.

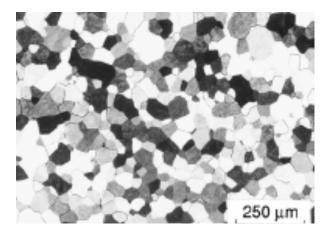


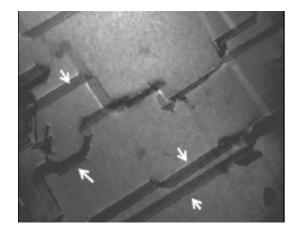
- Line Defects (1-D):
  - Dislocations (Linear defects around which atoms are "dislocated" from their equilibrium lattice positions).

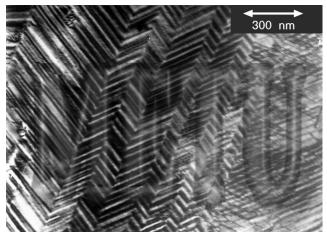




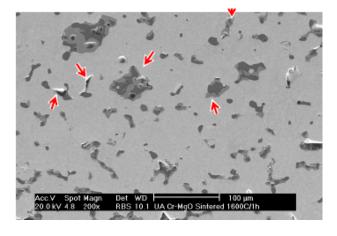
- Planar Defects (2-D):
  - > Grain boundaries, twin boundaries, stacking faults.

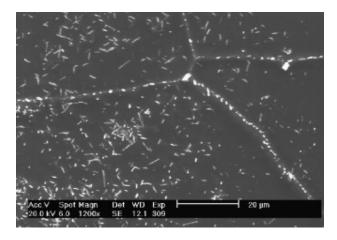




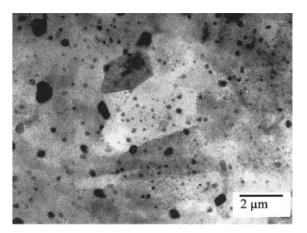


- Volume Defects (3-D):
  - > Voids, inclusions, precipitates, dispersed particles.

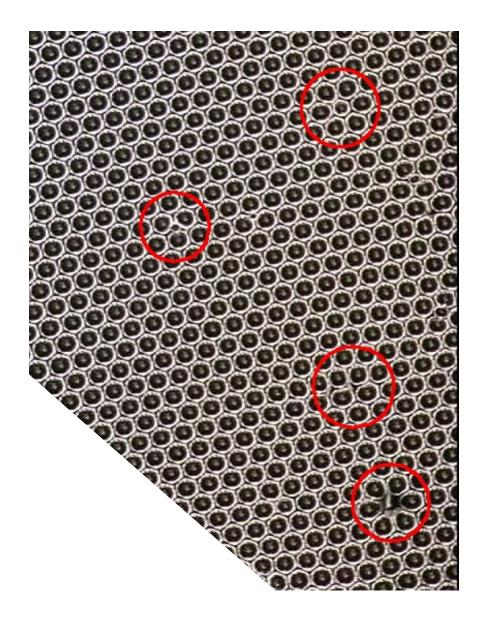


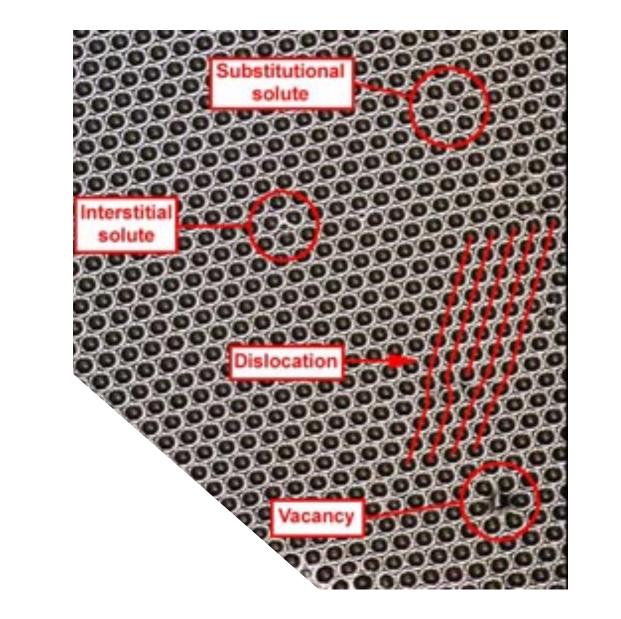


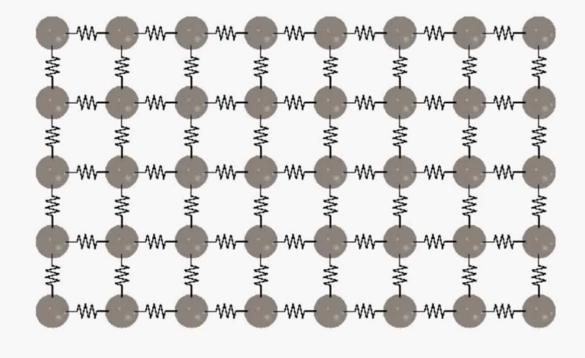




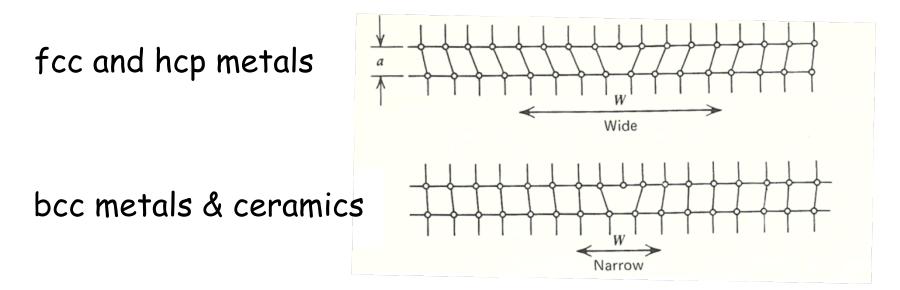








## Slip by Dislocation Movement

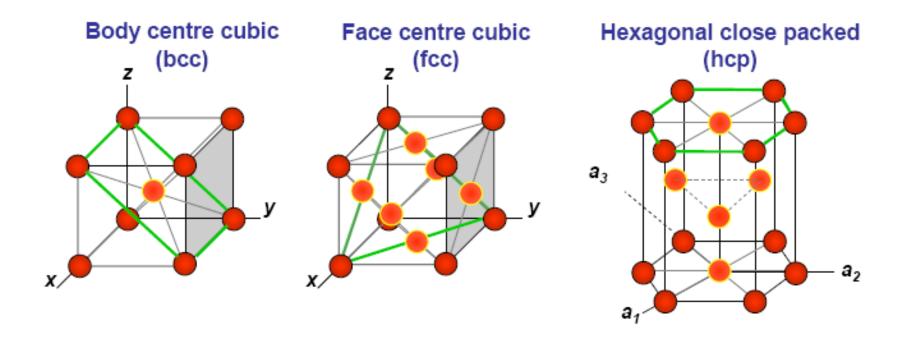


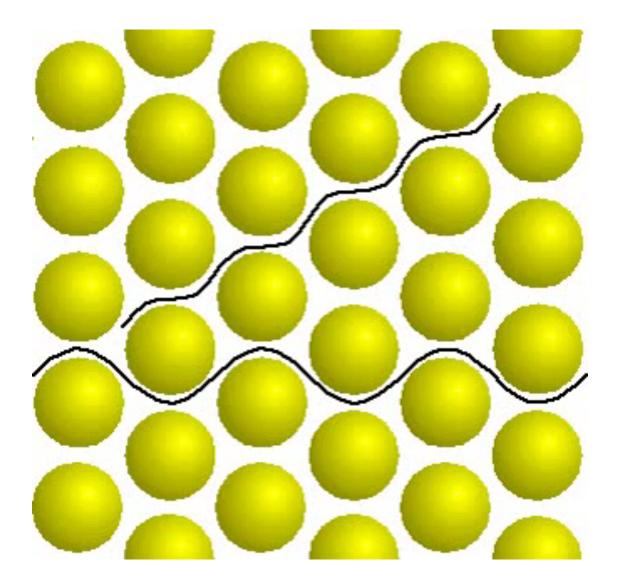
Magnitude of Peierls stress depends on w.

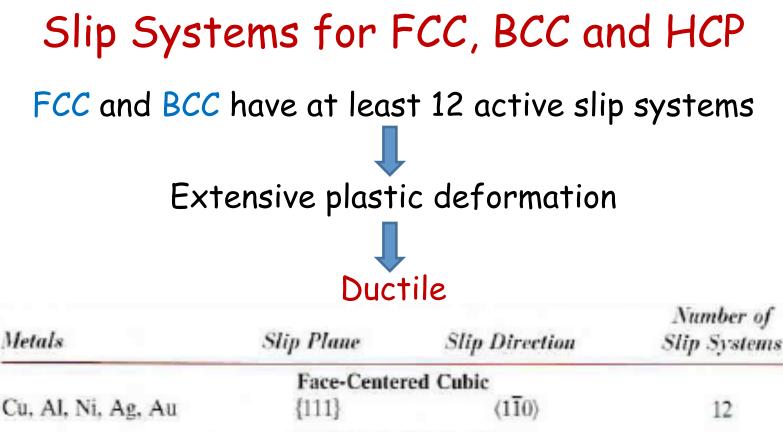
- > If w i, interfacial energy i, elastic energy ?.  $\tau_p \approx \frac{2G}{1-\upsilon} \exp\left(-\frac{2\pi w}{b}\right)$
- When the crystal is complex without highly closepacked planes, dislocations tend to be immobile causing brittleness.

# Slip Plane

- Plastic deformation is generally confined to the lowindex planes, which has higher density of atom per unit area.
- The planes of greatest atomic density are also the most widely spaced planes for the crystal structure.

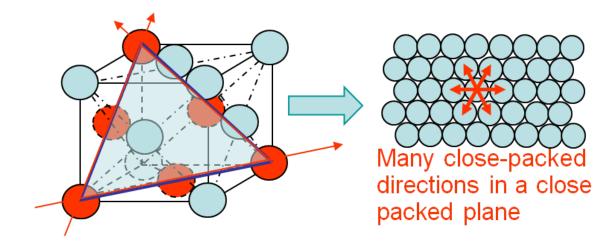


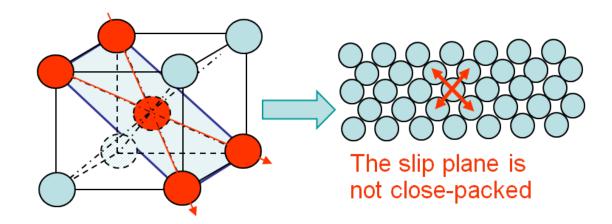




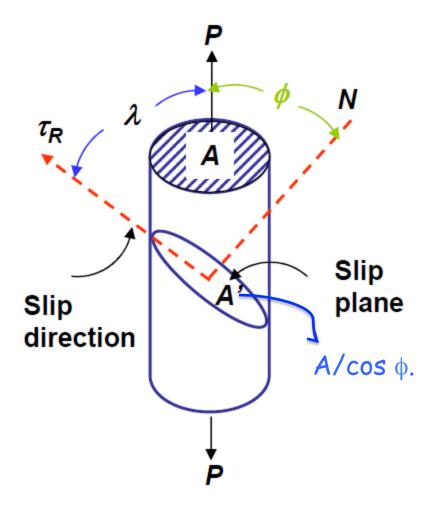
	Face-Center	ed Cubic	
Cu, Al, Ni, Ag, Au	{111}	$\langle 1\overline{1}0 \rangle$	12
	Body-Center	red Cubic	
α-Fe, W, Mo	{110}	(111)	12
α-Fe, W	{211}	$\langle \overline{1}11 \rangle$	12
α-Fc, K	{321}	$\langle \overline{1}11 \rangle$	24
	Hexagonal Clo	ose-Packed	
Cd, Zn, Mg, Ti, Be	{0001}	(1120)	3
Ti, Mg, Zr	{1010}	(1120)	3
Ti, Mg	{1011}	(1120)	6

### Slip Systems for FCC, BCC and HCP





#### Critical Resolved Shear Stress



The resolved shear stress:

$$\tau_{R} = \frac{P\cos\lambda}{A/\cos\phi} = \frac{P}{A}\cos\phi\cos\lambda$$

$$\begin{array}{ll} \varphi = \lambda = 45^{\circ} & \Longrightarrow & \tau_{\rm R} \text{ is max.} \\ \varphi = 0 \text{ or } \lambda = 0 \implies & \tau_{\rm R} = 0. \end{array}$$

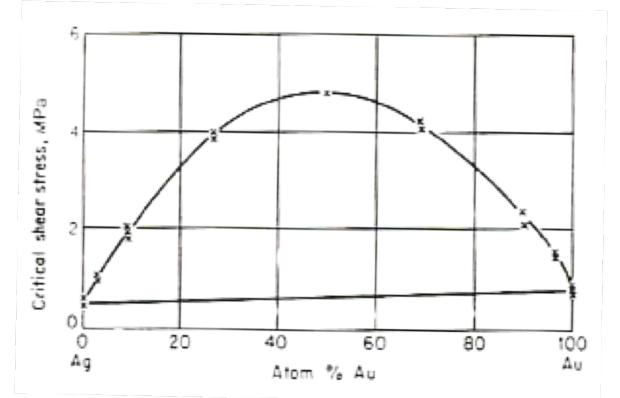
Slip occurs when  $\tau_R \ge \tau_{CRSS}$ 

HW: Determine the tensile stress that is applied along  $[1\overline{10}]$  axis of a silver crystal to cause slip on the  $(1\overline{11})[0\overline{11}]$  system. CRSS is 6 MPa.

#### CRSS in Real Metals

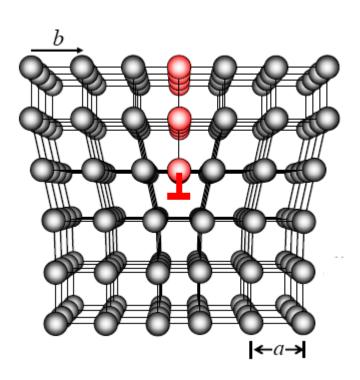
Defects Vacancies Impurity atoms Alloying elements

Critical resolved shear stress



## Types of Dislocation

• Edge dislocation: Linear defect that centers around the line, which is defined along the end of the extra portion of a plane of atoms (half plane).

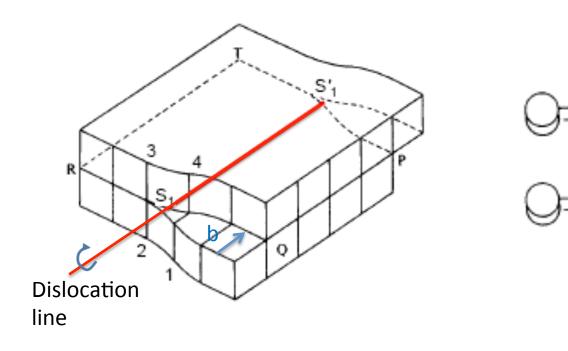


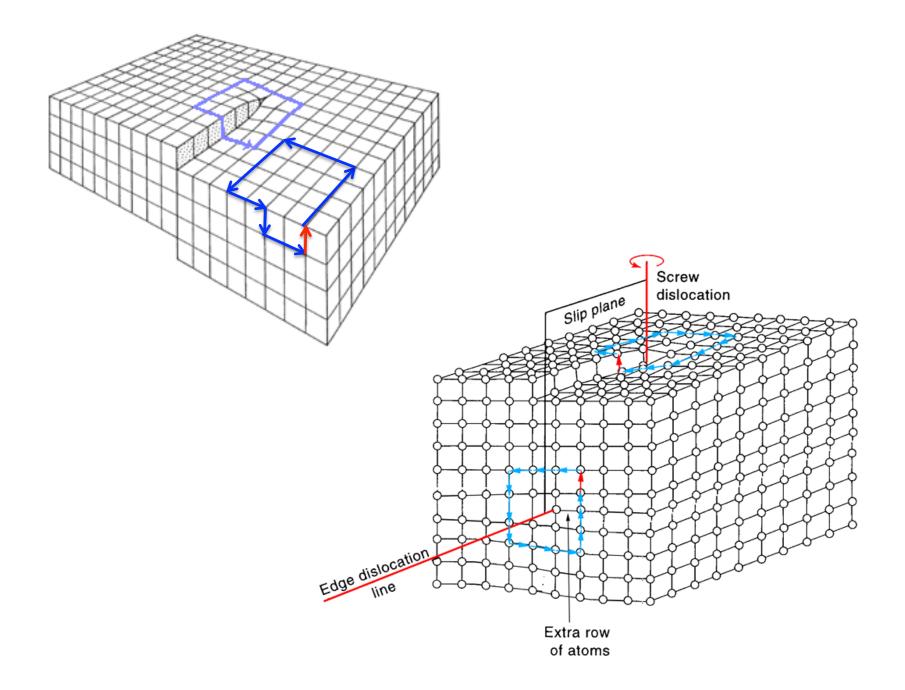
- Atoms above dislocation line are squeezed together (compressive), while those below are pulled apart (tensile), causing localized lattice distortion.
- The amount of displacement (Burgers vector, b) of the dislocation is always perpendicular to the dislocation line.

## Types of Dislocation

- Screw dislocation may be thought of as being formed by applying a shear stress to produce a distortion.
  - The dislocation line is parallel to its Burgers vector, b or slip vector.

(b)





## Characteristics of Dislocations

<b>Dislocation Characteristic</b>	Type of Dislocation	
	Edge	Screw
Slip direction	Parallel to b	Parallel to b
Relation between dislocation line and b	Perpendicular	Parallel
Process by which dislocations can leave slip plane	Climb	Cross-slip

- Dislocations can terminate at free surfaces, or at grain or phase boundaries; but never within the crystal.
- Dislocations must form closed loops or networks with branches that terminate at a surface.
- The junction point within a network is called a node.